Diode Semiconductor Device - Page 1 of 1



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#### Inclosure Material:

Metal

**Overall Length:** 

1.253 inches

# Mounting Facility Quantity:

1

## Electrode Internally-electrically Connected To Case:

Cathode

**Mounting Method:** 

Threaded stud

## Overall Width Across Flats:

Between 0.424 inches and 0.437 inches

Thread Size:

0.190 inches

Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

5.1 breakdown voltage, dc

## Voltage Tolerance In Percent:

-5.0 to 5.0

#### **Current Rating Per Characteristic:**

490.00 milliamperes voltage regulator diode current and 1.84 amperes repetitive peak forward current

#### **Power Rating Per Characteristic:**

10.0 watts small-signal input power, common-collector preset

#### Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius case

#### **Test Data Document:**

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

#### **Thread Series Designator:**

Unf

# Terminal Type And Quantity:

1 threaded stud and 1 tab, solder lug

# **Specification Data:**

81349-mil-s-19500/272 government specification

Shelf Life:

N/a

Unit Of Measure:

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## Demilitarization:

No

Fiig:

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